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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







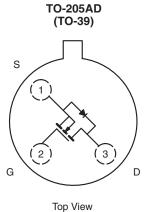
2N6661, 2N6661-2, 2N6661JANTX, 2N6661JANTXV

www.vishay.com

Vishay Siliconix

N-Channel 90 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	90				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	4				
Configuration	Single				



FEATURES

- Military Qualified
- Low On-Resistence: 3.6 Ω
- Low Threshold: 1.6 V
- Low Input Capacitance: 35 pF
- Fast Switching Speed: 6 ns
- Low Input and Output Leakage

BENEFITS

- Guaranteed Reliability
- Low Offset Voltage
- Low-Voltage Operation
- · Easily Driven Without Buffer
- High-Speed Circuits
- Low Error Voltage

APPLICATIONS

- Hi-Rel Systems
- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- · Battery Operated Systems
- Solid-State Relays

ORDERING INFORMATION					
PART	PACKAGE	DESCRIPTION/DSCC PART NUMBER	VISHAY ORDERING PART NUMBER		
2N6661		Commercial	2N6661		
		Commercial, Lead (Pb)-free	2N6661-E3		
2N6661-2		See -2 Flow Document	2N6661-2		
2N6661JANTX	TO-205AD	JANTX2N6661 (std Au leads)	2N6661JTX02		
	(TO-39)	JANTX2N6661 (with solder)	2N6661JTXL02		
		JANTX2N6661P (with PIND)	2N6661JTXP02		
2N6661JANTXV		JANTXV2N6661 (std Au leads)	2N6661JTXV02		
		JANTXV2N6661P (with PIND)	2N6661JTVP02		

ABSOLUTE MAXIMUM RATINGS ($T_A = 25 ^{\circ}C$, unless othe	rwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V _{DS}	90	V
Gate-Source Voltage		V _{GS}	± 20	
Continuous Drain Current (T _J = 150 °C)	T _C = 25 °C	-	0.86	
	T _C = 100 °C	I _D	0.54	Α
Pulsed Drain Current ^a		I _{DM}	3	
Maximum Power Dissipation	T _C = 25 °C	В	6.25	10/
	T _A = 25 °C	P _D	0.725	W
Thermal Resistance, Junction-to-Ambient ^b		R _{thJA}	170	°C/W
Thermal Resistance, Junction-to-Case		R _{thJC}	20	-C/W
Operating Junction and Storage Temperature R	ange	T.I. T _{sta}	- 55 to 150	°C

Notes

- a. Pulse width limited by maximum junction temperature.
- b. Not required by military spec.



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SPECIFICATIONS (T _A = 25 °C	C, unless o	otherwise not	ed)						
		TEST CONDITIONS		LIMITS					
PARAMETER	SYMBOL			MIN.	TYP.b	MAX.	UNIT		
Static									
Drain-Source Breakdown Voltage	V_{DS}	V_{DS}	$= 0 \text{ V}, I_D = 10$) μΑ	90	125	-		
		$V_{DS} = V_{GS}$, $I_D = 1$ mA $T_A = -55$ °C		0.8	1.6	2	V		
Gate-Source Threshold Voltage	V _{GS(th)}			T _A = - 55 °C	-	1.8	2.5	V	
				T _A = 125 °C	0.3	1.3	-		
Cata Bady Laglaga	1	V _{GS} = ± 20 V	, V _{DS} :	s = 0 V	-	-	± 100		
Gate-Body Leakage	I _{GSS}	VGS = ± 20 V		T _A = 125 °C	-	-	± 500	nA	
Zava Cata Valtaga Dvain Cuwant		V _{GS} = 0 V	V_{DS}	= 72 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}		S = 0 V	T _A = 125 °C	-	-	100	μA	
On-State Drain Current ^b	I _{D(on)}	V _{GS} = 10 V	V _{DS}	= 10 V	-	1.8	-	mA	
	R _{DS(on)}	V _{GS} = 5 V	I _D = 0.3 A		-	3.8	5.3		
Drain-Source On-State Resistanceb		V _{GS} = 10 V	I _D	= 1 A	-	3.6	4	Ω	
			V _{GS} = 10 V	T _A = 125 °C ^d	-	6.7	7.5	1	
Forward Transconductanceb	9 _{fs}	V _{DS} = 7.5 V, I _D = 0.475 A		170	340	-	mS		
Diode Forward Voltage	V _{SD}	V _{GS} = 0 V	I _S =	0.86 A	0.7	0.9	1.4	V	
Dynamic	·\					'	,	,	
Input Capacitance	C _{iss}				-	35	50		
Output Capacitance	Coss	$V_{GS} = 0 \text{ V}$ $V_{DS} = 25$			-	15	40		
Reverse Transfer Capacitance	C _{rss}	$V_{GS} = 0 V$ $V_{DS} = 25 V, f = 1 MHz$	-	2	10	pF			
Drain-Source Capacitance	C _{ds}	1			-	30	-		
Switching ^c	•								
Turn-On Time	t _{ON}	V _{DD} :	= 25 V, R _L = 3	23 Ω	-	6	10		
Turn-Off Time	t _{OFF}	$I_D \cong 1 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 23 \Omega$		-	8	10	ns		

Notes

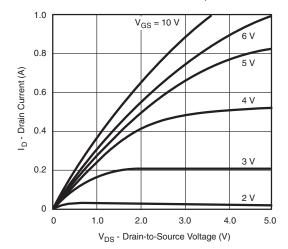
- a. FOR DESIGN AID ONLY, not subject to production testing.
- b. Pulse test: PW \leq 300 μ s duty cycle \leq 2 %.
- c. Switching time is essentially independent of operating temperature.
- d. This parameter not registered with JEDEC.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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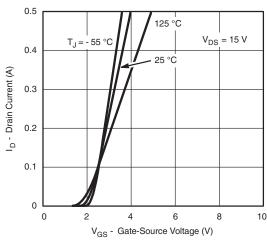
Vishay Siliconix

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

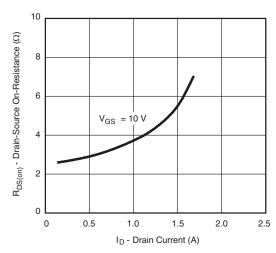


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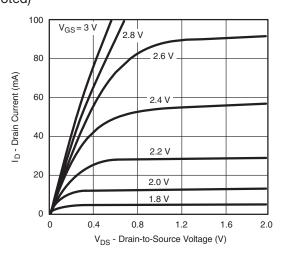
Ohmic Region Characteristics



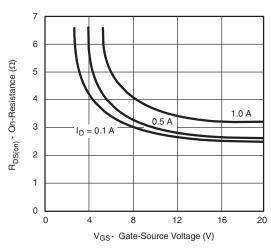
Transfer Characteristics



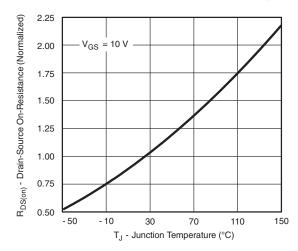
On-Resistance vs. Drain Current



Output Characteristics for Low Gate Drive



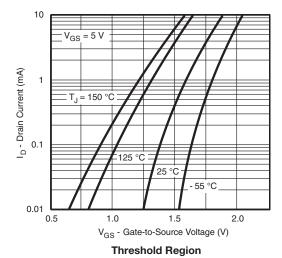
On-Resistance vs. Gate-to-Source Voltage



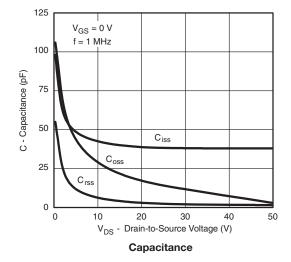
Normalized On-Resistance vs. Junction Temperature

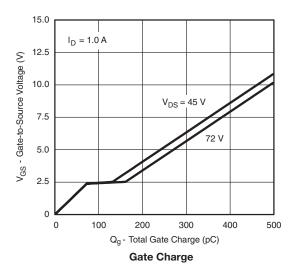
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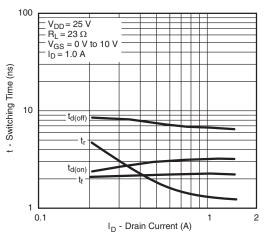
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

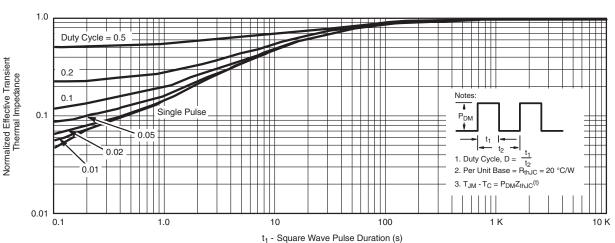


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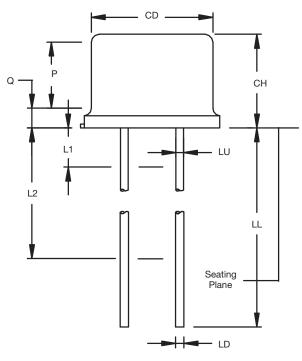
Load Condition Effects on Switching

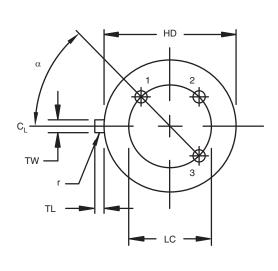
Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70225.



TO-205AD (TO-39 TALL LID)





DIM.	INC	IES	MILLIMETERS		
	MIN.	MAX.	MIN.	MAX.	
CD	0.305	0.335	7.75	8.51	
CH	0.240	0.260	6.10	6.60	
HD	0.335	0.370	8.51	9.40	
LC ⁽⁶⁾	0.200) TP	5.08	3 TP	
LD ⁽⁷⁾⁽⁸⁾	0.016	0.021	0.41	0.53	
LL (7)(8)	0.500	0.750	12.70	19.05	
LU (7)(8)	0.016	0.019	0.41	0.48	
L1 ⁽⁷⁾⁽⁸⁾	_	0.050	_	1.27	
L2 ⁽⁷⁾⁽⁸⁾	0.250	_	6.35		
P ⁽⁵⁾	0.100	_	2.54 -		
Q ⁽⁴⁾	_	0.050	- 1.2		
r ⁽⁹⁾	_	0.010	_	0.25	
TL ⁽³⁾	0.029	0.045	0.74	1.14	
TW ⁽²⁾	0.028	0.034	0.71	0.86	
α (6)	45°	TP	45°	TP	

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DWG: 5511

Notes

- (1) Dimensions are in inches. Metric equivalents are given for general information only.
- (2) Beyond radius (r) maximum, TW shall be held for a minimum length of 0.011" (0.028 mm).
- (3) Dimension TL measured from maximum HD.
- (4) Outline in this zone is not controlled.
- (5) Dimension CD shall not vary more than 0.010 (0.25 mm) in zone P. This zone is controlled for automatic handling.
- (6) Leads at guage plane 0.054" + 0.001", 0.000" (1.37 mm + 0.03 mm, 0.00 mm) below seating plane shall be within 0.007" (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.
- (7) LU applies between L1 and L2, LD applies between L2 and L maximum. Diameter is uncontrolled in L1 and beyond LL minimum.
- (8) All three leads.
- (9) Radius (r) applies to both inside corners of tab.
- (10) Drain is electrically connected to the case.

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